

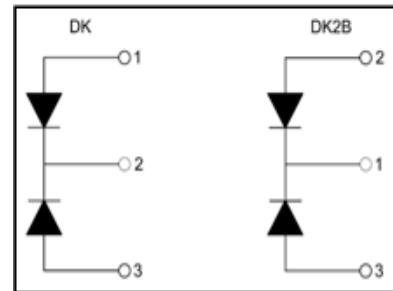
## PRODUCT FEATURES

- Ultrafast Reverse Recovery Time
- Soft Reverse Recovery Characteristics
- Low Reverse Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Inductance Package



## APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply (UPS)
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- Power Factor Correction (PFC) Circuit



## ABSOLUTE MAXIMUM RATINGS

$T_C=25^{\circ}\text{C}$  unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
$V_R$	Maximum D.C. Reverse Voltage		1700	V
$V_{RRM}$	Maximum Repetitive Reverse Voltage		1700	V
$I_{F(AV)}$	Average Forward Current	$T_C=80^{\circ}\text{C}$ , Per Diode	200	A
		$T_C=80^{\circ}\text{C}$ , 20KHz, Per Diode	150	A
$I_{F(RMS)}$	RMS Forward Current	$T_C=80^{\circ}\text{C}$ , Per Diode	280	A
$I_{FSM}$	Non-Repetitive Surge Forward Current	$t=10\text{ms}$ , 50Hz, Sine	2000	A
		$t=8.3\text{ms}$ , 60Hz, Sine	2200	A
$I^2t$	$I^2t$ (For Fusing)	$t=10\text{ms}$ , 50Hz, Sine	20000	$\text{A}^2\text{s}$
		$t=8.3\text{ms}$ , 60Hz, Sine	24200	$\text{A}^2\text{s}$
$P_D$	Power Dissipation		893	W
$T_J$	Junction Temperature		-40 to +150	$^{\circ}\text{C}$
$T_{STG}$	Storage Temperature Range		-40 to +125	$^{\circ}\text{C}$
$V_{isol}$	Insulation Test Voltage	AC, $t=1\text{min}$	3000	V
Torque	Module-to-Sink	Recommended (M6)	3~5	N·m
Torque	Module Electrodes	Recommended (M6)	3~5	N·m
$R_{\theta JC}$	Thermal Resistance	Junction-to-Case	0.14	$^{\circ}\text{C}/\text{W}$
Weight			160	g

**ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I <sub>RM</sub>	Reverse Leakage Current	V <sub>R</sub> =1700V	--	--	5	mA
		V <sub>R</sub> =1700V, T <sub>J</sub> =125°C	--	--	20	mA
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> =200A	--	1.8	2.25	V
		I <sub>F</sub> =200A, T <sub>J</sub> =125°C	--	1.95	--	V
t <sub>rr</sub>	Reverse Recovery Time	I <sub>F</sub> =1A, V <sub>R</sub> =30V, di <sub>F</sub> /dt=-200A/μs	--	120	--	ns
t <sub>rr</sub>	Reverse Recovery Time	V <sub>R</sub> =850V, I <sub>F</sub> =200A	--	750	--	ns
I <sub>RRM</sub>	Max. Reverse Recovery Current	di <sub>F</sub> /dt=-200A/μs, T <sub>J</sub> =25°C	--	40	--	A
t <sub>rr</sub>	Reverse Recovery Time	V <sub>R</sub> =850V, I <sub>F</sub> =200A	--	1.4	--	μs
I <sub>RRM</sub>	Max. Reverse Recovery Current	di <sub>F</sub> /dt=-200A/μs, T <sub>J</sub> =125°C	--	50	--	A
t <sub>rr</sub>	Reverse Recovery Time	V <sub>R</sub> =850V, I <sub>F</sub> =200A	--	900	--	ns
I <sub>RRM</sub>	Max. Reverse Recovery Current	di <sub>F</sub> /dt=-1000A/μs, T <sub>J</sub> =125°C	--	150	--	A

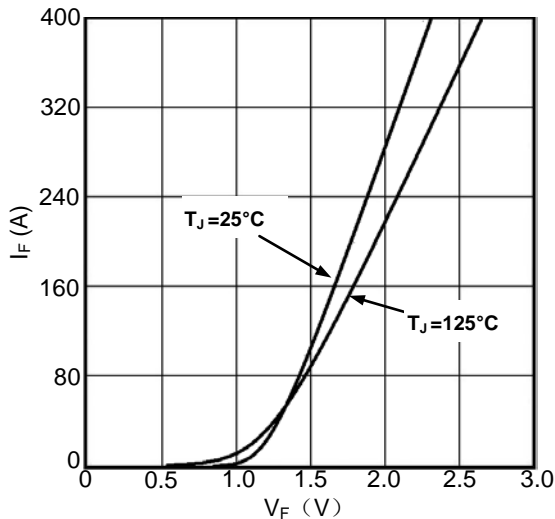


Figure1. Forward Voltage Drop vs Forward Current

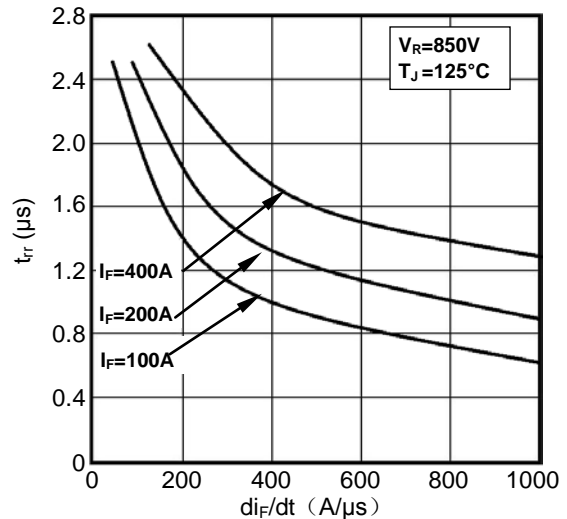


Figure2. Reverse Recovery Time vs di<sub>F</sub>/dt

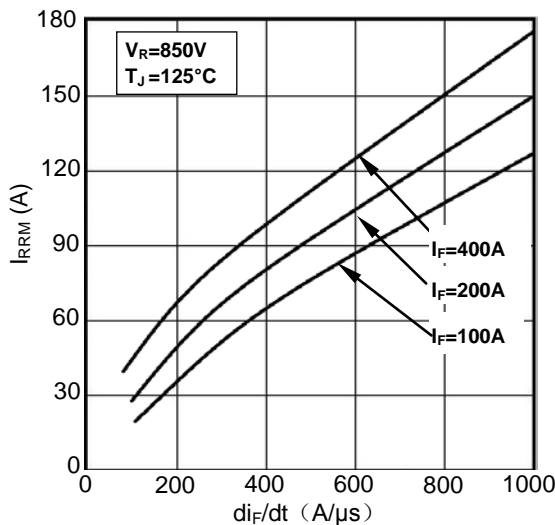


Figure3. Reverse Recovery Current vs di<sub>F</sub>/dt

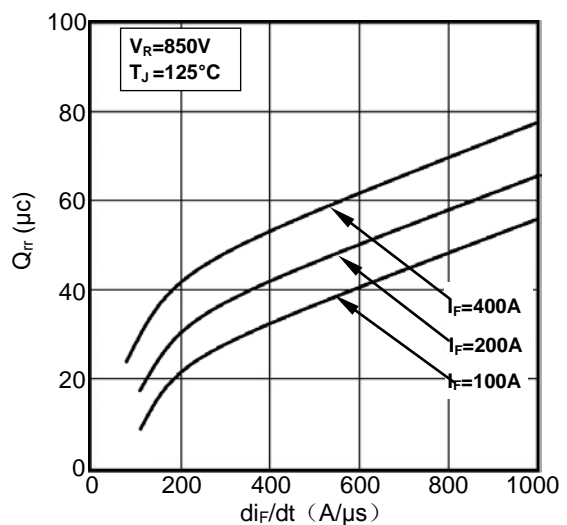


Figure4. Reverse Recovery Charge vs di<sub>F</sub>/dt

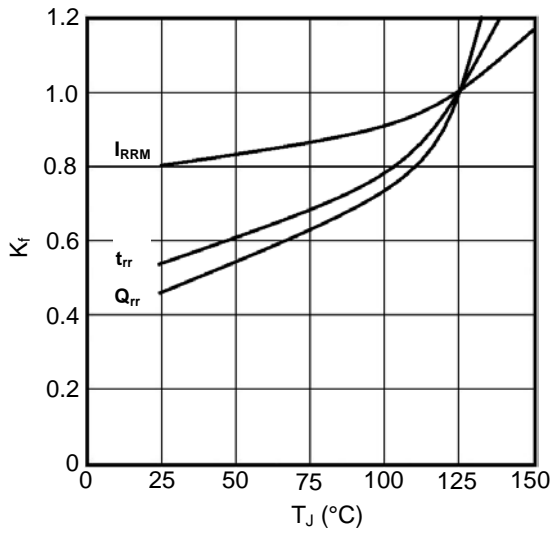


Figure5. Dynamic Parameters vs Junction Temperature

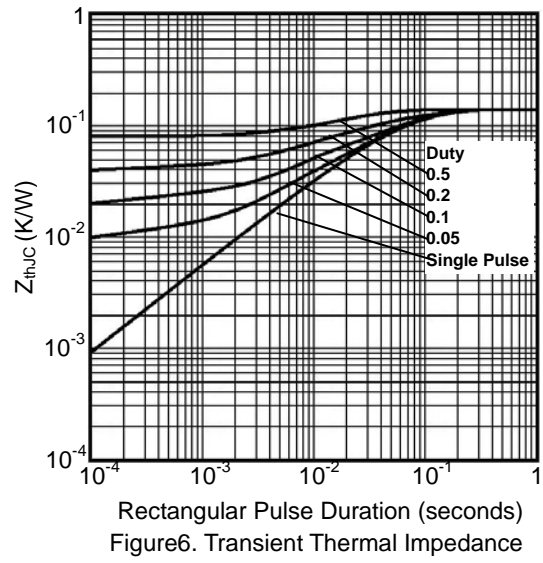
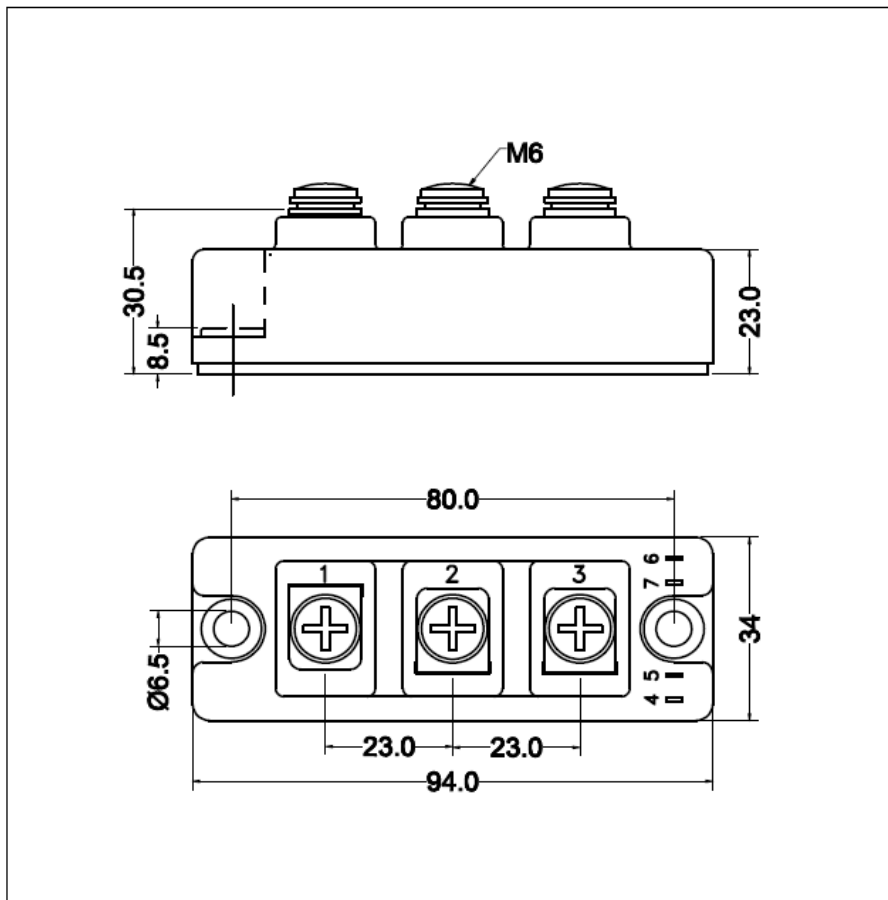


Figure6. Transient Thermal Impedance



Dimensions (mm)  
Figure7. Package Outline